

# Effect of NiO addition on the sintering and grain growth behaviour of BaTiO<sub>3</sub>

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## Abstract

The sintering and grain growth behaviour of NiO-doped BaTiO<sub>3</sub> in air are investigated in the present study. The solubility of NiO in BaTiO<sub>3</sub> is determined by measuring the lattice constant of BaTiO<sub>3</sub> as a function of NiO content. The solubility is around 0.13 wt% as sintering temperature ranges from 1250 to 1330°C. The densification of BaTiO<sub>3</sub> is retarded due to the solution of NiO. Possible mechanism is proposed. The existence of residual NiO inclusions also reduces the densification rate. The adding of NiO inhibits the grain growth of BaTiO<sub>3</sub>. For the BaTiO<sub>3</sub> doped with 0.13 wt% NiO, no abnormal grains are observed. © 1998 Elsevier Science Limited and Techna S.r.l. All rights reserved

*Keywords:* A. sintering; A. grain growth; D. BaTiO<sub>3</sub>

## 1. Introduction

Barium titanate (BaTiO<sub>3</sub>) is widely used as a dielectric material for its high dielectric constant. Due to the capacitance is increased with increasing area, multilayer structure BaTiO<sub>3</sub> is developed to fulfil the requirement on size reduction. The material frequently used as the inner electrode for the multilayer capacitors is Pd/Ag alloys. Due to the cost of Pd is high, nickel is considered as an alternative [1]. The nickel may be oxidised during binder pyrolysis in air. Nickel oxide then tends to diffuse into BaTiO<sub>3</sub> to change its dielectric properties [2]. The capacitance is also increased with decreasing thickness. However, the thickness of the dielectric is reduced, the influence of Ni solutes on the dielectric properties can be more noticeable.

The solubility of NiO in the BaTiO<sub>3</sub> lattice is reported as 0.6 to 1.0 wt% [3–5]. The valence state of Ni ions in BaTiO<sub>3</sub> lattice is proved as Ni<sup>2+</sup> [4,6]. The Ni ions may occupy the Ba<sup>2+</sup> sites [5,7] or Ti<sup>4+</sup> sites [3,6]. The dominated sintering mechanism for BaTiO<sub>3</sub> is reported as grain boundary diffusion [8,9]. The rate control species for diffusion as proposed by Lewis et al. is Ti ion vacancy [10]. Polycrystalline BaTiO<sub>3</sub> readily experiences abnormal grain growth during sintering. Considerable studies have focused on the grain growth behaviour of

BaTiO<sub>3</sub>. The addition of Dy<sub>2</sub>O<sub>3</sub>, [11] Nb<sub>2</sub>O<sub>5</sub> [12] or Sc<sub>2</sub>O<sub>3</sub> [13] inhibits the grain growth of BaTiO<sub>3</sub>. The presence of NiO can also reduce the size of BaTiO<sub>3</sub> grains [14].

To the knowledge of the present authors, the effect of NiO on the sintering behaviour of BaTiO<sub>3</sub> has not been determined. In the present study, the nickel oxide particles are mixed intimately with BaTiO<sub>3</sub> powder before sintering. The solubility of NiO in BaTiO<sub>3</sub> is determined first. The effect of Ni solutes or undissolved NiO inclusions, on the sintering behaviour of BaTiO<sub>3</sub> can then be determined.

## 2. Experimental procedures

The BaTiO<sub>3</sub> powder (no. 219-6, Ferro Co., USA) having a Ba/Ti ratio of 0.995 was mixed with various amounts of nickel nitrate (Johnson Matthey Chem. Co., USA). The powder mixtures were milled together in ethyl alcohol for 4 h. The grinding media used was zirconia balls. The slurry was dried using a rotary evaporator. The dried lumps were crushed and passed through a plastic sieve. The sieved powder was calcined at 500°C in air for 1 h. The temperature was higher than the decomposition temperature of nickel nitrate. The calcined powder was then formed by uniaxially pressing at 25 MPa into disks (10 mm in diameter and about

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5 mm in thickness). The green density of specimens was measured by the geometric method. The pore size distribution of green compacts was characterised by mercury porosimetry (Autopore II 9220, Micromeritics Instrument Co., USA).

Sintering was performed at a temperature varied from 1250–1370°C in air. The dwelling time was 2 h. The heating and cooling rates were 3°C min<sup>-1</sup>. Shrinkage kinetics was determined by a differential dilatometer (Theta Co., USA). Phase identification was performed by X-ray diffractometry (XRD). A very slow scanning rate (0.01 degree 2θ/s) was also used to determine the lattice constant ratio of *c* over *a* by using the (002) and (200) reflections. The size of NiO crystals in the calcined powder was determined by measuring the line broadening of the NiO XRD peaks. The fired density was determined by the water displacement method. The polished specimens were prepared by grinding with SiC particles and by polishing with Al<sub>2</sub>O<sub>3</sub> particles. The polished surfaces were chemically etched with a HCl–HF solution to reveal the grain boundaries. The microstructure was observed with scanning electron microscopy (SEM). The volume fraction of abnormal grains was determined by measuring the area fraction of abnormal grains in SEM micrographs. The size of BaTiO<sub>3</sub> and NiO grains was determined by using the linear intercept technique. Samples for transmission electron microscopy (TEM, Jeol 100CXII) were mechanically thinned to about 50 μm. The thinned samples were subsequently dimpled to a thickness of 20 μm in the centre and then ion-milled to perforation of the central disk region. These samples were observed at the voltage of 100 kV.

### 3. Results and discussion

There are only tetragonal BaTiO<sub>3</sub> and cubic NiO detected in the calcined powder by the XRD analysis. The morphology of the calcined powder is shown in Fig. 1. On the surface of the BaTiO<sub>3</sub> particles, small rectangular NiO particles are observed, Fig. 1(b). The size of NiO crystals as determined by the XRD line broadening technique is around 30 nm. The pore size distribution of green bodies is shown in Fig. 2. Bimodal pore size distribution is noted in all green compacts. It suggests that the powder is strongly agglomerated [15]. The strong agglomerates are survived after the die-pressing stage. The mean pore size within the agglomerates (intra-agglomerate) is about 0.18 μm. The amount of intra-agglomerate pores is little. Most pores are located at inter-agglomerate sites. The size of inter-agglomerate pores for pure BaTiO<sub>3</sub> is 0.26 μm. As 0.13 wt% NiO is added, the size of inter-agglomerate pores is virtually unchanged. However, as NiO content is higher than 1.3 wt%, the size of inter-agglomerate

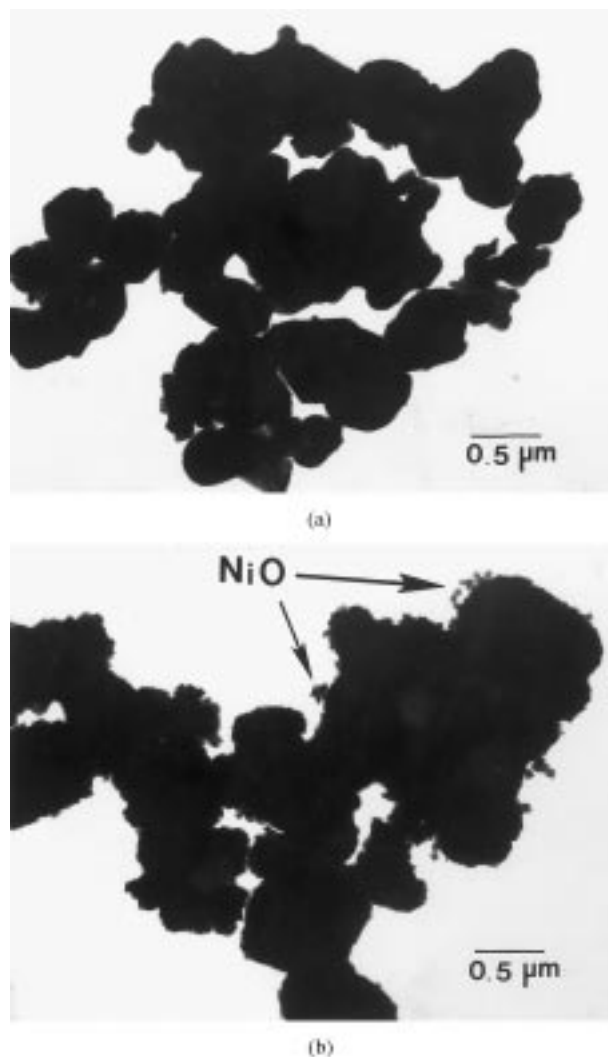


Fig. 1. The morphology of the calcined powders which contain (a) 0 and (b) 12.4 wt% NiO.

pores increases with increasing NiO content. The surface of BaTiO<sub>3</sub> particles is coated with small NiO particles. The presence of small NiO particles can push the BaTiO<sub>3</sub> particles further apart. The size of inter-agglomerate pore is thus increased.

The green density is shown as a function of NiO content in Fig. 3. As the NiO content is below 1.3 wt%, the green density is around 53%. As the NiO content is higher than 1.3 wt%, the green density is decreased due to the size of pores is enlarged, Fig. 2. The XRD patterns of the sintered specimens are shown in Fig. 4. Only tetragonal BaTiO<sub>3</sub> phase and cubic NiO phase are detected as sintering temperature is below 1330°C (Fig. 4(a)). There is no NiO detected in the BaTiO<sub>3</sub>–1.3 wt% NiO specimen. However, due to the detection limit of the XRD analysis, the XRD analysis can only suggest that the solubility of NiO in BaTiO<sub>3</sub> is below 1.3 wt%. A monoclinic phase, Ba<sub>6</sub>Ti<sub>17</sub>O<sub>40</sub> phase, is found as the sintering temperature is 1370°C (Fig. 4(b)).

The presence of the  $Ba_6Ti_{17}O_{40}$  phase suggests the presence of an eutectic liquid during sintering.

Fig. 5 shows typical XRD patterns obtained by using the slow scanning rate. The splitting of (002) and (200) reflections of tetragonal phase decreases with increasing NiO content. The lattice constant ratio of  $c$  over  $a$  of  $BaTiO_3$  is shown as a function of NiO content in Fig. 6. Two factors affect the  $c/a$  ratio. The factors are the grain size and the solution of NiO in  $BaTiO_3$ . Alrt reported that  $c/a$  ratio is reduced with decreasing grain size as the grain size is smaller than  $1\ \mu m$  [16]. The  $c/a$  ratio is constant for the specimens with grain size above  $1.5\ \mu m$ . To be shown latter, the grain size measured for

the specimens investigated in the present study is larger than  $1.2\ \mu m$ . The major factor to reduce the  $c/a$  ratio is thus the solution of NiO in  $BaTiO_3$  lattice. The  $c/a$  ratio is decreased as NiO content is increased (Fig. 6). As the NiO content is higher than a certain value, the values of  $c/a$  ratio are stabilized. The solubility of NiO in  $BaTiO_3$  can thus be determined by using Fig. 6. As the sintering temperature ranges from  $1250$  to  $1330^\circ C$ , the solubility of NiO in  $BaTiO_3$  is about  $0.13\ wt\%$ . As the sintering temperature is  $1370^\circ C$ , the solubility is higher than  $0.13\ wt\%$  and lower than  $1.3\ wt\%$ . It may be due to the presence of the eutectic liquid that enhances the solubility. The solubility limit obtained in the present study is lower than the values reported by others [3–5]. The discrepancy may result from the different raw material used.

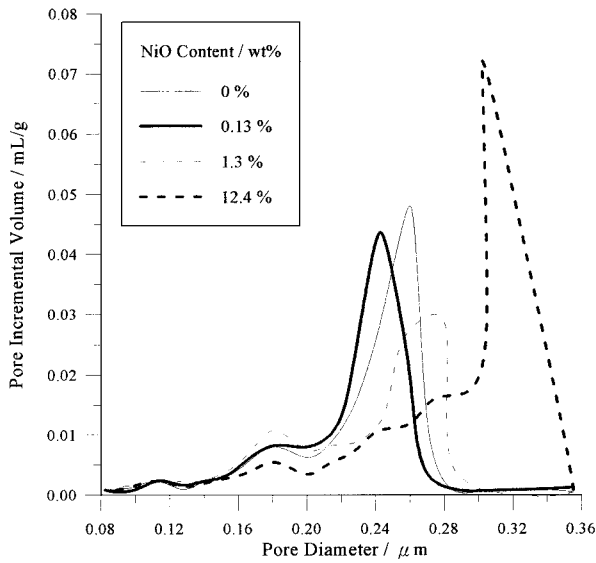


Fig. 2. The pore size distribution for the green bodies containing different NiO content.

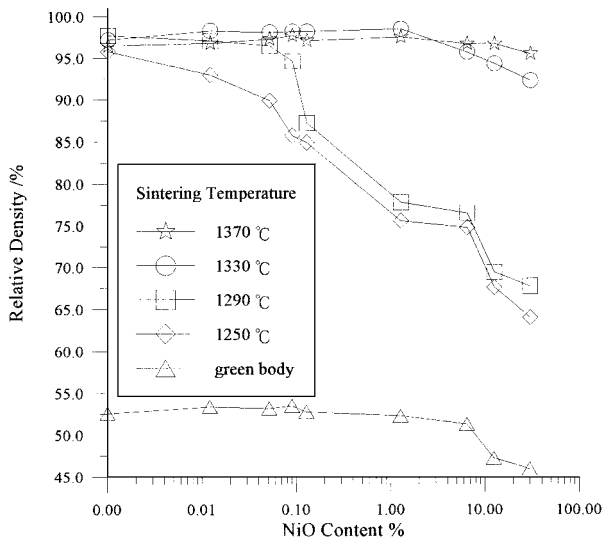


Fig. 3. The relative density of NiO-doped  $BaTiO_3$  specimens as a function of NiO content.

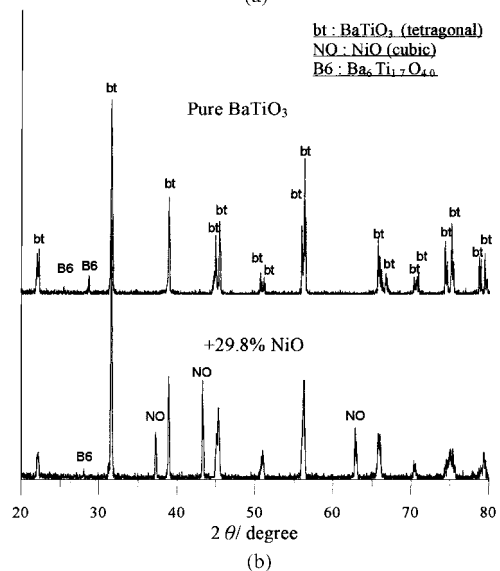
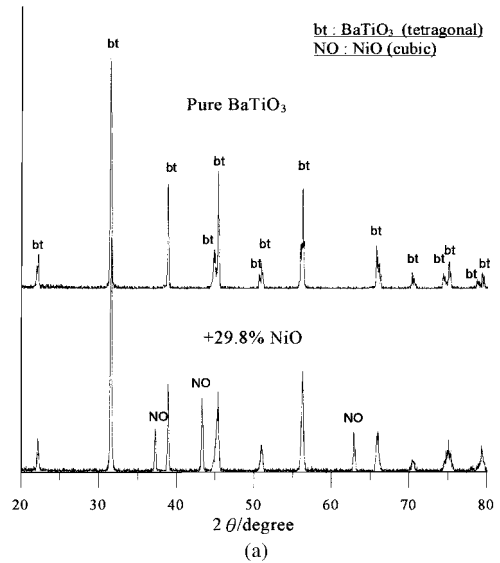


Fig. 4. The XRD patterns of undoped and  $29.8\ wt\%$  NiO-doped  $BaTiO_3$  specimens sintered at (a)  $1330^\circ C$  and (b)  $1370^\circ C$ .

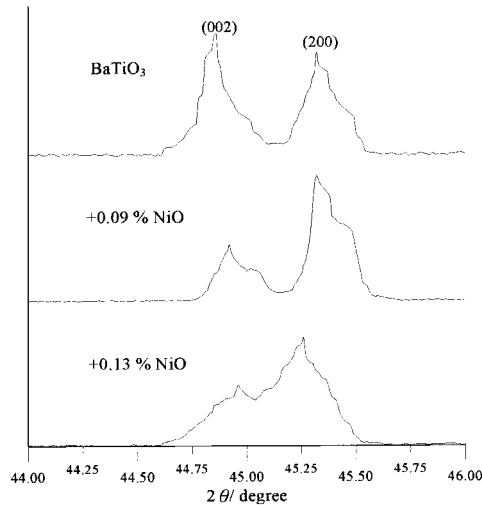


Fig. 5. The (002) and (200) diffraction peaks for NiO-doped BaTiO<sub>3</sub> specimens. The specimens are sintered at 1330°C for 2 h.

When the coordination number is 6, the ionic radius of the Ti<sup>4+</sup> and Ni<sup>2+</sup> is 0.61 and 0.69 Å, respectively. The ionic radius of Ba<sup>2+</sup> ion is 1.59 Å as the coordination number is 12. Although the valence of Ni ion is the same as that of Ba ion, the ionic radius of Ni<sup>2+</sup> is much smaller than that of Ba<sup>2+</sup>. The Ni<sup>2+</sup> is more likely to replace the Ti<sup>4+</sup> for their similar ionic size. This has been proved recently [17]. Tzing and Tuan found that *n*-type semiconducting BaTiO<sub>3</sub> is obtained as sintering is taken place in a reducing atmosphere. The presence of Ni ion increased the electrical resistivity. It suggested that Ni ion acts as electron acceptor in BaTiO<sub>3</sub> lattice. The replacement of Ti<sup>4+</sup> by Ni<sup>2+</sup> may accompany the formation of oxygen vacancy as [6]

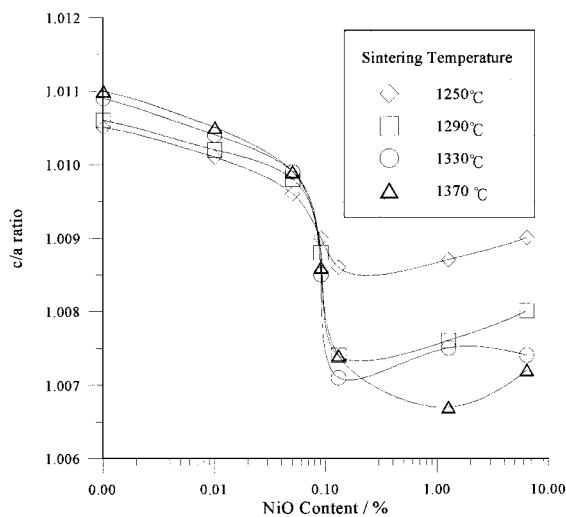
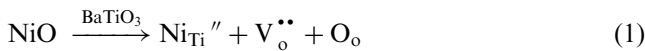


Fig. 6. The lattice constant *c/a* ratio of NiO-doped BaTiO<sub>3</sub> specimens as a function of NiO content.

The BaTiO<sub>3</sub> crystal is distorted due to the solution of Ni. The fraction of the increase in *a*-axis is higher than that in *c*-axis. The *c/a* ratio is thus reduced. The low solubility may result from different valence state between Ti<sup>4+</sup> and Ni<sup>2+</sup>.

The relative density of sintered specimens is also shown in Fig. 3. The relative density of the undoped BaTiO<sub>3</sub> is higher than 95%. As NiO is added, the relative density is decreased with the increase of NiO content as sintering temperature is below 1290°C. It indicates that the addition of NiO retards the densification of BaTiO<sub>3</sub>. The shrinkage is isotropic for all the specimens prepared in the present study. The relative density during sintering can thus be calculated by using the linear shrinkage data from dilatometer. The densification kinetics for the NiO-doped BaTiO<sub>3</sub> are shown in Fig. 7. A constant heating rate, 3°C min<sup>-1</sup> is used during sintering in the dilatometer. The densification rate can be estimated by differentiating the relative density with temperature (Fig. 8). Two peaks are found in the densification rate curves. There is a similarity between the densification rate and the pore size distribution curves, (Figs. 2 and 8). It implies that the first peak in the densification rate curves is resulted from the shrinkage of the small intra-agglomerate pores. The second peak is resulted from the shrinkage of the inter-agglomerate pores.

The densification is mainly started roughly from 1150°C (Fig. 8). It is interesting to examine whether the solution of NiO in BaTiO<sub>3</sub> or the densification takes place first. A 0.13 wt% NiO-doped BaTiO<sub>3</sub> is sintered at 1100°C for 1 min. The *c/a* ratio for the doped specimen is 1.0095 which is less than the value for the undoped BaTiO<sub>3</sub>. It thus indicates that NiO starts to dissolve into BaTiO<sub>3</sub> before 1100°C. The solution of NiO in BaTiO<sub>3</sub> takes place before the densification. When the added

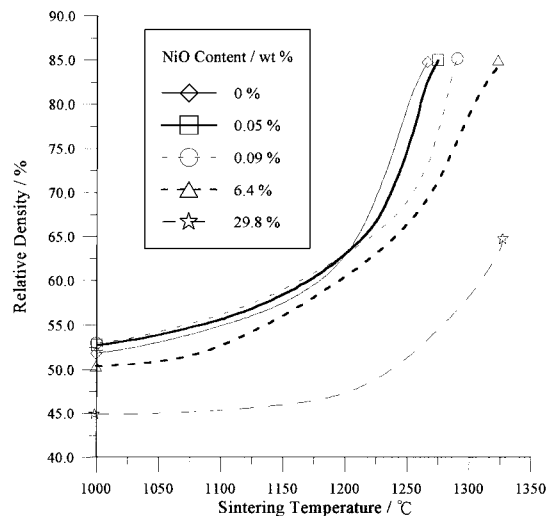


Fig. 7. The densification curves for NiO-doped BaTiO<sub>3</sub> specimens as a function of temperature.

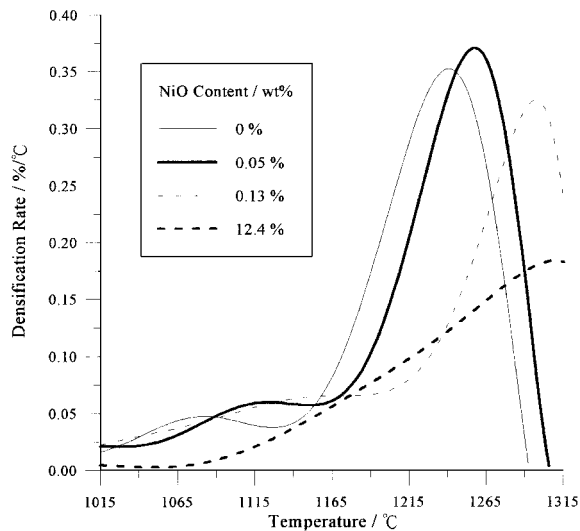


Fig. 8. The densification rate of NiO-doped BaTiO<sub>3</sub> specimens as a function of temperature.

NiO content is below the solubility limit, higher temperature is needed to reach maximum densification rate. It indicates the densification of BaTiO<sub>3</sub> is retarded due to the presence of Ni solute. The solution of NiO into BaTiO<sub>3</sub> increases the concentration of  $V_{\text{O}}^{\bullet}$  Eq. (1). As Schottky-type, defect is predominant in BaTiO<sub>3</sub> [18], the increase of the concentration of  $V_{\text{O}}^{\bullet}$  reduces the concentration of  $V_{\text{Ti}}^{\prime\prime}$ . The Ti vacancy is the rate controlling species because it has the highest activation energy of diffusion in BaTiO<sub>3</sub> [10]. The solution of NiO thus retards the densification of BaTiO<sub>3</sub>.

As the NiO content is higher than the solubility limit, residual NiO inclusions can be observed, (Fig. 9). The presence of NiO inclusions between BaTiO<sub>3</sub> grains increases the inter-diffusion distance. The densification rate and final density are thus reduced (Figs. 3 and 8).



Fig. 9. A TEM micrograph of the 1.3 wt% NiO-doped BaTiO<sub>3</sub> specimen. The specimen is sintered at 1330 °C.

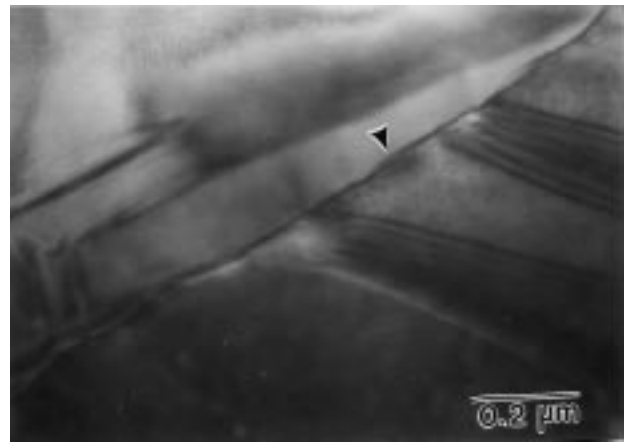


Fig. 10. The liquid phase observed in the undoped BaTiO<sub>3</sub> specimen sintered at 1330 °C.

According to the BaO–TiO<sub>2</sub> phase diagram [19], an eutectic liquid phase is formed above 1312 °C in the TiO<sub>2</sub> excess system. The liquid phase is observed in the specimens sintered at 1330 °C (Fig. 10). The presence of the liquid phase also enhances the densification of NiO-doped BaTiO<sub>3</sub> specimens (Fig. 3). As the sintering temperature is 1370 °C, the relative density of the 30 wt% NiO-doped BaTiO<sub>3</sub> is higher than 95%.

Typical microstructures of pure BaTiO<sub>3</sub> and NiO-doped BaTiO<sub>3</sub> are shown in Fig. 11. The size of abnormal and small grains is shown in Fig. 12. The volume fraction of abnormal grain is shown in the bracket in the figure. Abnormal grains can be observed in the BaTiO<sub>3</sub> specimen sintered at 1250 °C. This temperature is lower than the BaTiO<sub>3</sub>–Ba<sub>6</sub>Ti<sub>17</sub>O<sub>40</sub> eutectic temperature [19]. As shown in Fig. 2, agglomerates are presented in the green compacts. The shrinkage of the intra-agglomerate pores takes place in the very beginning of the sintering (Fig. 8). The abnormal grains may nucleate from the dense agglomerates. Chemical inhomogeneity can reduce the liquid formation temperature. The possible formation of liquid phase may also play some role on the formation of abnormal grains. The volume fraction of abnormal grains, the size of abnormal and of small grains increase with increasing sintering temperature. The size of BaTiO<sub>3</sub> grains in the undoped BaTiO<sub>3</sub> specimens grow to a size of 50 μm as they are sintered above 1330 °C, (Fig. 11(b)). Many pores are trapped in the abnormal grains. It leads to the decrease of relative density.

The microstructure of a NiO-doped BaTiO<sub>3</sub> sintered at 1330 °C is shown in Fig. 11(c). The added NiO content is 0.13 wt%. The relative density is about 98.2%. No abnormal grains are observed due to the existence of some NiO inclusions. The size of NiO inclusions in all the NiO-doped BaTiO<sub>3</sub> is smaller than 0.7 μm. When NiO content is below the solubility limit, the inhibition of grain growth can be attributed to the retardation of

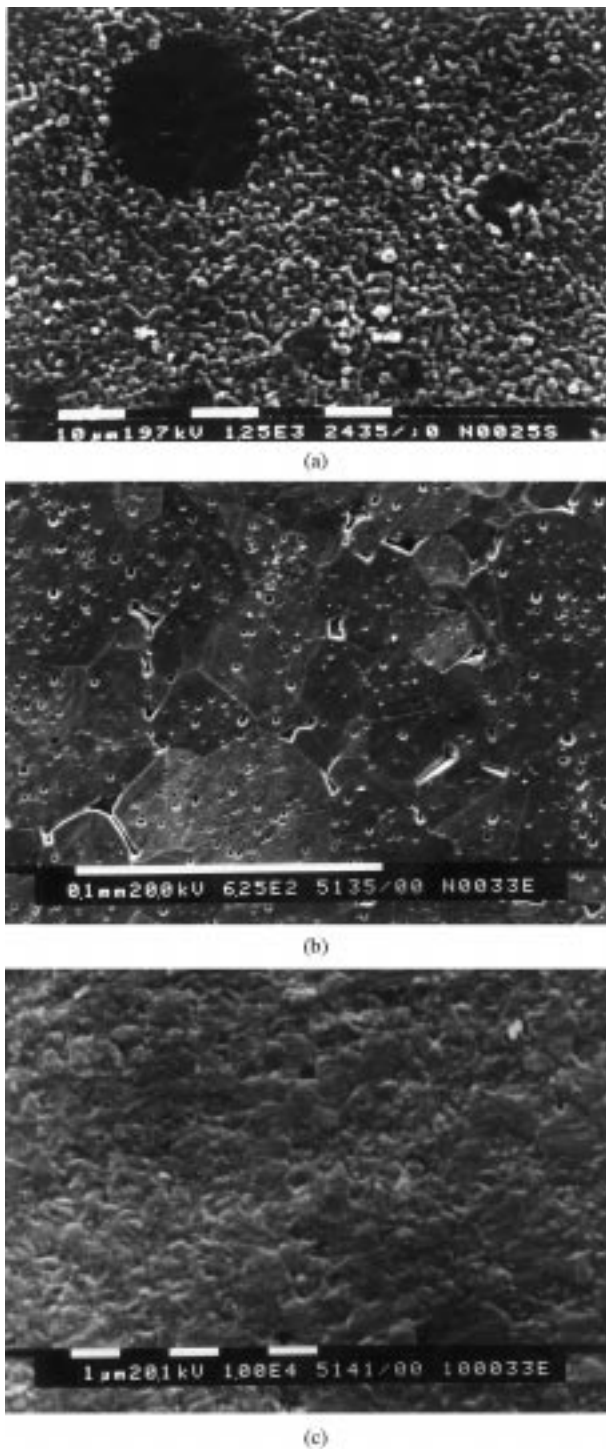


Fig. 11. The SEM micrographs of (a) BaTiO<sub>3</sub> sintered at 1250°C, (b) BaTiO<sub>3</sub> sintered at 1330°C and (c) 0.13 wt% NiO-doped BaTiO<sub>3</sub> sintered at 1330°C.

densification [20]. When NiO content is higher than the solubility limit, the presence of NiO inclusions prohibits the movement of grain boundaries (Fig. 9). The microstructure of these specimens is refined despite the presence of liquid phase.

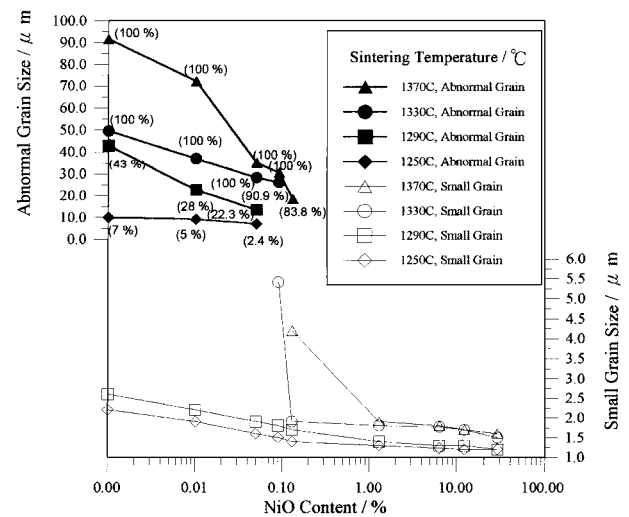


Fig. 12. The average size of BaTiO<sub>3</sub> grains in the NiO-doped BaTiO<sub>3</sub> specimens. The number in the bracket indicates the volume fraction of abnormal BaTiO<sub>3</sub> grains.

#### 4. Conclusions

The following conclusions can be made from the present study:

1. Around 0.13 wt% NiO is dissolved into BaTiO<sub>3</sub> as the sintering temperature varies from 1250 to 1330°C. The presence of the eutectic liquid increases the solubility.
2. When the added NiO content is below the solubility limit, higher temperature is needed to reach maximum densification rate. The densification of BaTiO<sub>3</sub> is retarded due to the presence of Ni solute.
3. The presence of residual NiO inclusions reduces the sintered density. Raising the sintering temperature to form an eutectic liquid enhances the sinterability.
4. Both the Ni solute and NiO inclusions reduce the grain size of BaTiO<sub>3</sub>. The abnormal grains are totally suppressed as the NiO content is higher than the solubility limit.

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